

Silicon N-Channel MOSFET

Applications

Interfacing, switching (30V, 100mA)

Features

Low on-resistance

Fast switching speed

Low voltage drive (2.5V) makes this ideal for portable equipment

Drive circuits can be simple

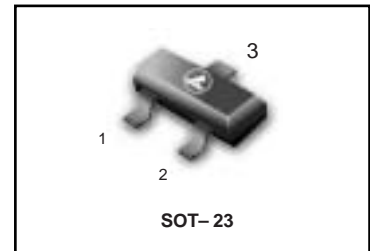
Parallel use is easy

we declare that the material of product compliance with RoHS requirements.

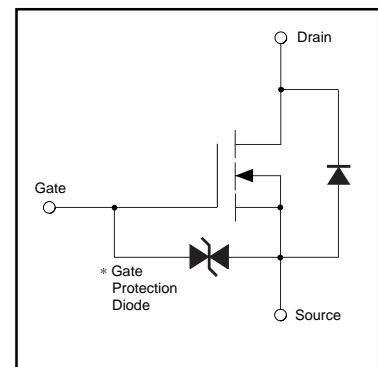
ORDERING INFORMATION

Device	Marking	Shipping
L2SK3019LT1G	KN	3000/Tape & Reel
L2SK3019LT3G	KN	10,000/Tape & Reel

L2SK3019LT1G



Equivalent circuit



A protection diode is included between the gate and the source terminals to protect the diode against static electricity when the product is in use. Use a protection circuit when the fixed voltages are exceeded.

Maximum Ratings and Thermal Characteristics (T_A = 25°C unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V _{DS}	30	V
Gate-Source Voltage	V _{GS}	± 20	
Continuous Drain Current	I _D	± 100	mA
Pulsed Drain Current ¹⁾	I _{DM}	± 400	
Total Power Dissipation ²⁾	P _D	0.15	W
Operating Junction and Storage Temperature Range	T _J , T _{stg}	-55 to 150	°C

1) P_w ≤ 10μs, Duty cycles ≤ 1%

2) With each pin mounted on the recommended lands.

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●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Gate-source leakage	I_{GSS}	-	-	± 1	μA	$V_{GS}=\pm 20V, V_{DS}=0V$
Drain-source breakdown voltage	$V_{(BR)DSS}$	30	-	-	V	$I_D=10\mu A, V_{GS}=0V$
Zero gate voltage drain current	I_{DSS}	-	-	1.0	μA	$V_{DS}=30V, V_{GS}=0V$
Gate threshold voltage	$V_{GS(th)}$	0.8	-	1.5	V	$V_{DS}=3V, I_D=100\mu A$
Static drain-source on-state resistance	$R_{DS(on)}$	-	5	8	Ω	$I_D=10mA, V_{GS}=4V$
	$R_{DS(on)}$	-	7	13	Ω	$I_D=1mA, V_{GS}=2.5V$
Forward transfer admittance	$ Y_{fs} $	20	-	-	ms	$I_D=10mA, V_{DS}=3V$
Input capacitance	C_{iss}	-	13	-	pF	$V_{DS}=5V$
Output capacitance	C_{oss}	-	9	-	pF	$V_{GS}=0V$
Reverse transfer capacitance	C_{rss}	-	4	-	pF	$f=1MHz$
Turn-on delay time	$t_{d(on)}$	-	15	-	ns	$I_D=10mA, V_{DD}=5V$
Rise time	t_r	-	35	-	ns	$V_{GS}=5V$
Turn-off delay time	$t_{d(off)}$	-	80	-	ns	$R_L=500\Omega$
Fall time	t_f	-	80	-	ns	$R_G=10\Omega$

●Electrical characteristic curves

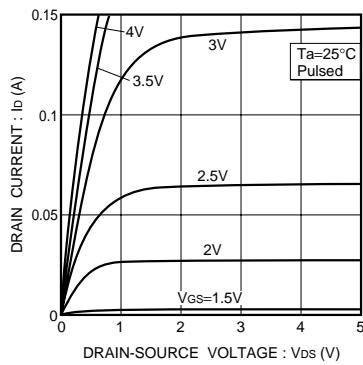


Fig.1 Typical output characteristics

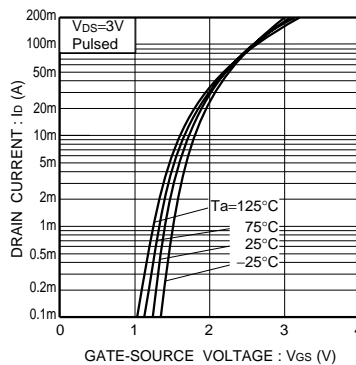


Fig.2 Typical transfer characteristics

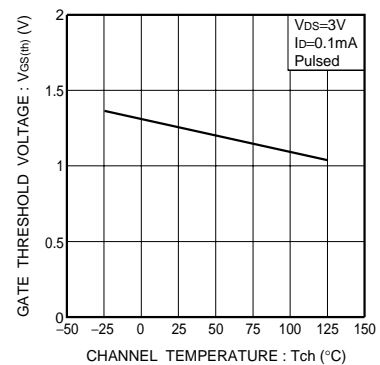


Fig.3 Gate threshold voltage vs. channel temperature

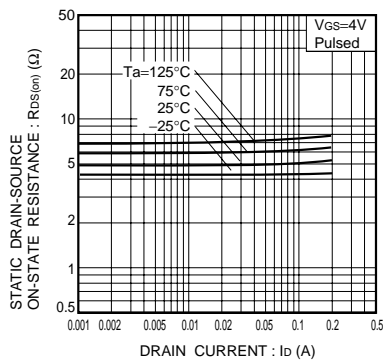


Fig.4 Static drain-source on-state resistance vs. drain current (I)

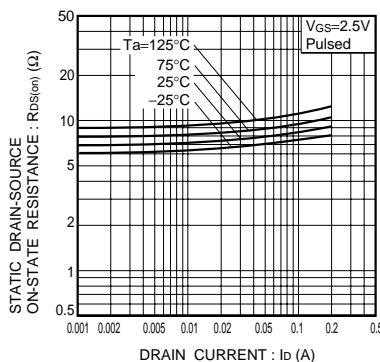


Fig.5 Static drain-source on-state resistance vs. drain current (II)

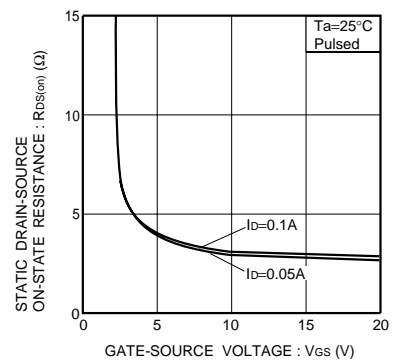


Fig.6 Static drain-source on-state resistance vs. gate-source voltage

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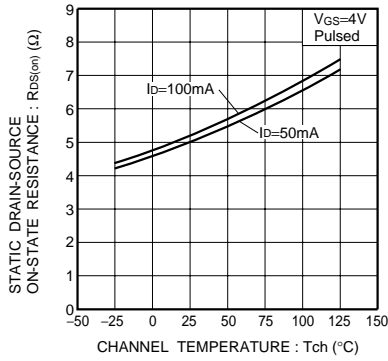


Fig.7 Static drain-source on-state resistance vs. channel temperature

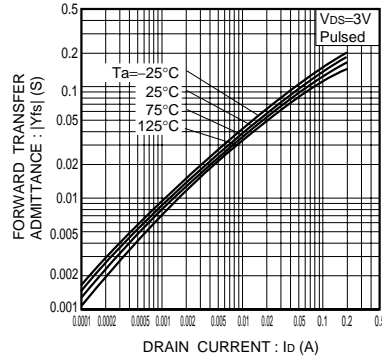


Fig.8 Forward transfer admittance vs. drain current

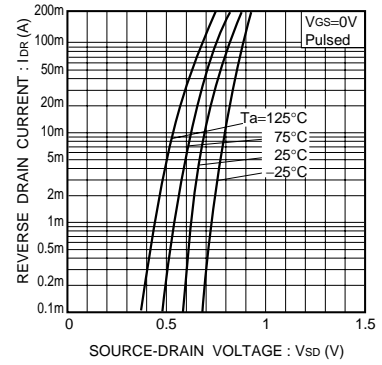


Fig.9 Reverse drain current vs. source-drain voltage (I)

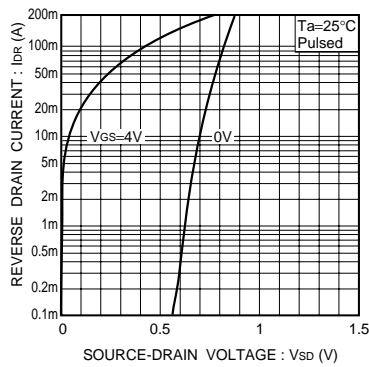


Fig.10 Reverse drain current vs. source-drain voltage (II)

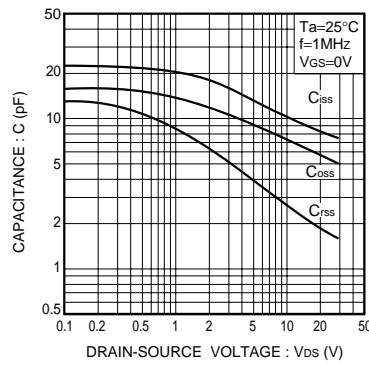


Fig.11 Typical capacitance vs. drain-source voltage

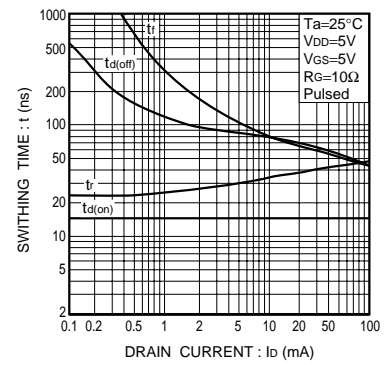


Fig.12 Switching characteristics (See Figures 13 and 14 for the measurement circuit and resultant waveforms)

● Switching characteristics measurement circuit

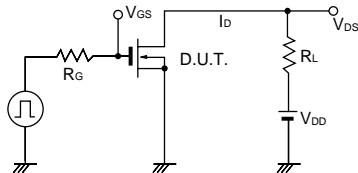


Fig.13 Switching time measurement circuit

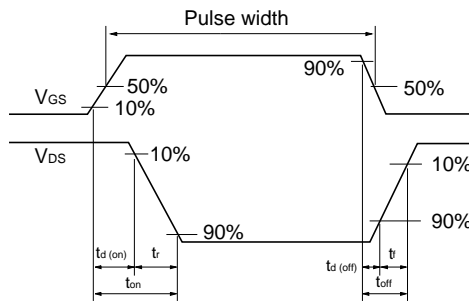


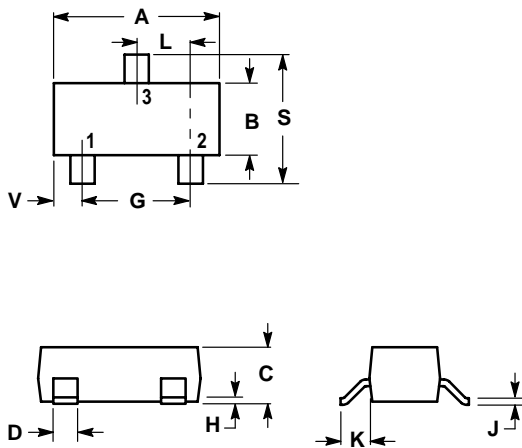
Fig.14 Switching time waveforms

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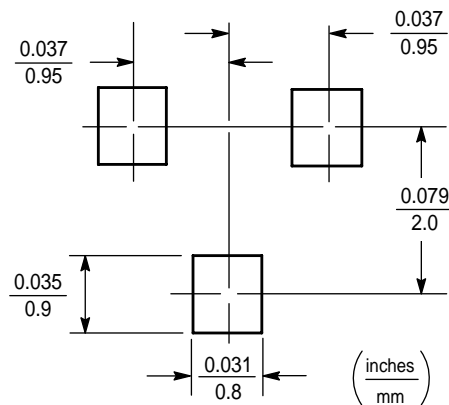
SOT-23

NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M,1982
2. CONTROLLING DIMENSION: INCH.



DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.1102	0.1197	2.80	3.04
B	0.0472	0.0551	1.20	1.40
C	0.0350	0.0440	0.89	1.11
D	0.0150	0.0200	0.37	0.50
G	0.0701	0.0807	1.78	2.04
H	0.0005	0.0040	0.013	0.100
J	0.0034	0.0070	0.085	0.177
K	0.0140	0.0285	0.35	0.69
L	0.0350	0.0401	0.89	1.02
S	0.0830	0.1039	2.10	2.64
V	0.0177	0.0236	0.45	0.60

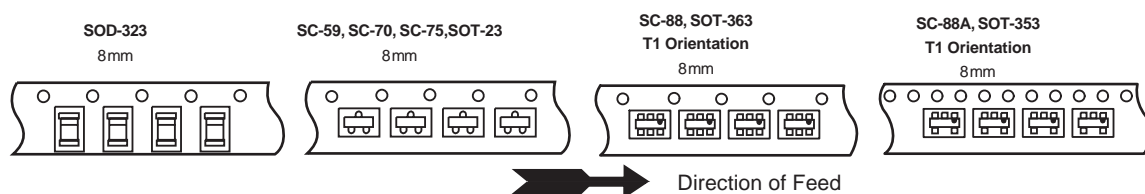


Tape & Reel and Packaging Specifications for Small-Signal Transistors, FETs and Diodes

Embossed Tape and Reel is used to facilitate automatic pick and place equipment feed requirements. The tape is used as the shipping container for various products and requires a minimum of handling. The antistatic/conductive tape provides a secure cavity for the product when sealed with the “peel-back” cover tape.

- Two Reel Sizes Available (7" and 13")
- Used for Automatic Pick and Place Feed Systems
- Minimizes Product Handling
- EIA 481, -1, -2
- SOT-23, SC-70/SOT-323, SC-89, SC-88/SOT-363, SC-88A/SOT-353, SOD-323, SOD-523 in 8 mm Tape

Use the standard device title and add the required suffix as listed in the option table below (Table 1). Note that the individual reels have a finite number of devices depending on the type of product contained in the tape. Also note the minimum lot size is one full reel for each line item, and orders are required to be in increments of the single reel quantity.

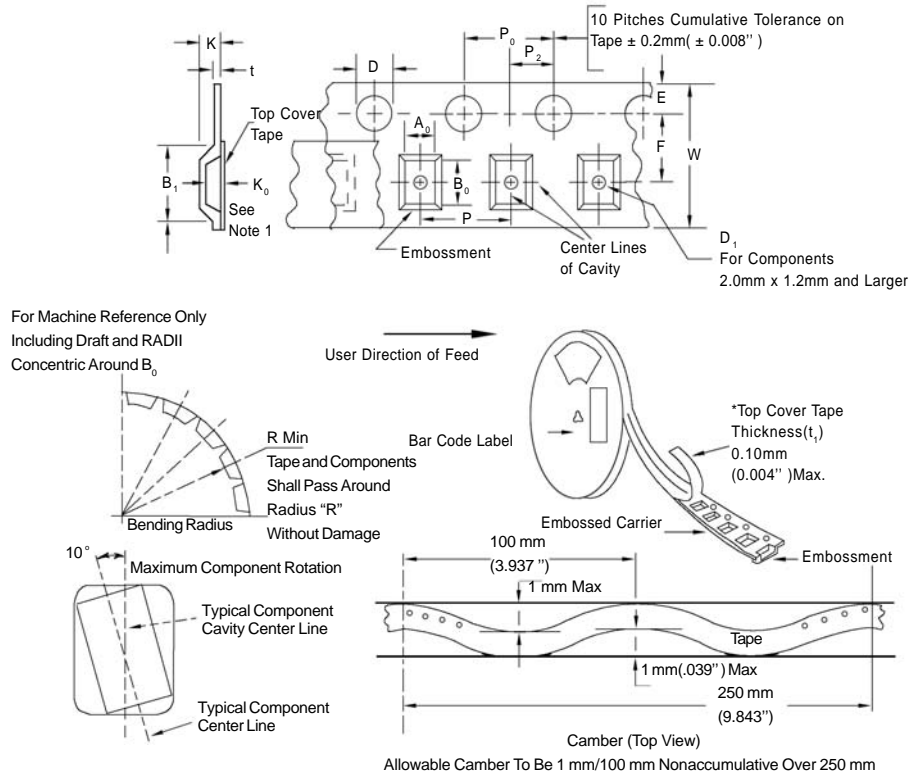


Typical Reel Orientations

Table 1. EMBOSSED TAPE AND REEL ORDERING INFORMATION

Package	Tape Width (mm)	Pitch mm	Reel Size mm(inch)	Devices Per Reel and Minimum Order Quantity	Device Suffix
SOT-23	8	4	178	(7)	3,000 T1
	8		330	(13)	10,000 T3
SC-70/SOT-323	8	4	178	(7)	3,000 T1
	8		330	(13)	10,000 T3
SC-89	8	4	178	(7)	3,000 T1
	8		330	(13)	10,000 T3
SC-88/SOT-363	8	4	178	(7)	3,000 T1
	8		330	(13)	10,000 T3
SC-88A/SOT-353	8	4	178	(7)	3,000 T1
	8		330	(13)	10,000 T3
SOD-323	8	4	178	(7)	3,000 T1
	8		330	(13)	10,000 T3
SOD-523	8	4	178	(7)	3,000 T1
	8		330	(13)	10,000 T3

EMBOSSSED TAPE AND REEL DATA FOR DISCRETES CARRIER TAPE SPECIFICATIONS



DIMENSIONS

Tape Size	B_1 Max	D	D_1	E	F	K	P_0	P_2	RMin	TMax	WMax
8mm	4.55mm (.179")	1.5+0.1mm - 0.0	1.0Min (.039")	1.75±0.1mm (.069±.004)	3.5±0.05mm (.138±.002")	2.4mmMax (.094")	4.0 ± 0.1mm (.157 ± .004")	2.0 ± 0.1mm (.079 ± .002")	25mm (.98")	0.6mm (.024")	8.3mm (.327")
12mm	8.2mm (.323")	(.059+.004" -0.0)	1.5mmMin (.060")		5.5±0.05mm (.217±.002")	6.4mmMax (.252")			30mm (1.18")		12 ± .30mm (.470±.012")
16mm	12.1mm (.476")				7.5±0.10mm (.295±.004")	7.9mmMax (.311")					16.3mm (.642")
24mm	20.1mm (.791")				11.5±0.1mm (.453±.004")	11.9mmMax (.468")					24.3mm (.957")

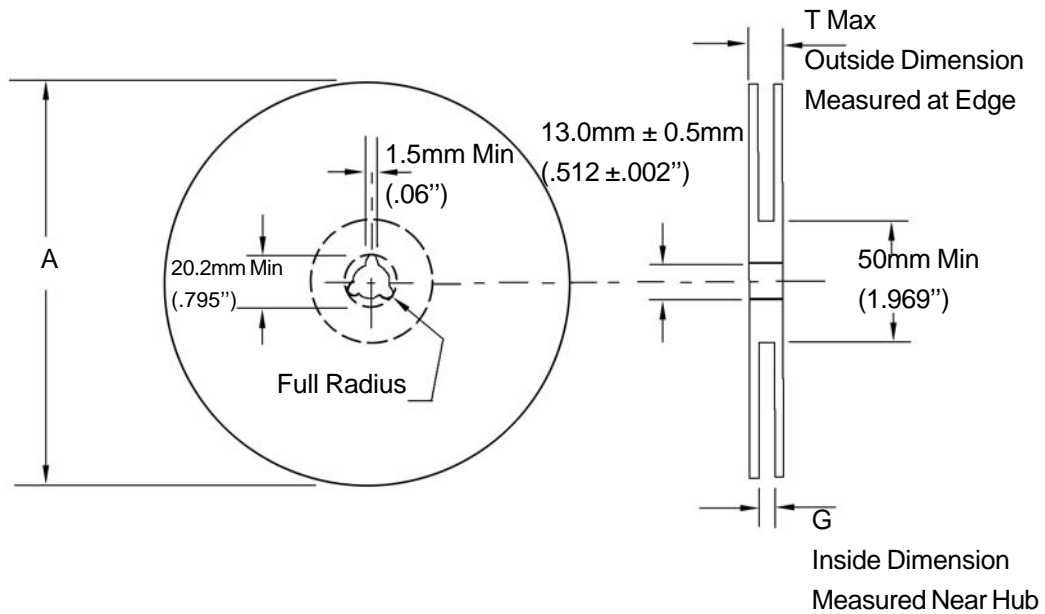
Metric dimensions govern - English are in parentheses for reference only.

NOTE 1: A_0 , B_0 , and K_0 are determined by component size. The clearance between the components and the cavity must be within .05 mm min. to .50 mm max.,

NOTE 2: the component cannot rotate more than 10° within the determined cavity.

NOTE 3: If B_1 exceeds 4.2 mm (.165") for 8 mm embossed tape, the tape may not feed through all tape feeders.

EMBOSSED TAPE AND REEL DATA FOR DISCRETES



Size	A Max	G	T Max
8 mm	330mm (12.992")	8.4mm+1.5mm, -0.0 (.33"+.059", -0.00)	14.4mm (.56")

Reel Dimensions

Metric Dimensions Govern — English are in parentheses for reference only

Storage Conditions

Temperature: 5 to 40 Deg.C (20 to 30 Deg. C is preferred)

Humidity: 30 to 80 RH (40 to 60 is preferred)

Recommended Period: One year after manufacturing

(This recommended period is for the soldering condition only. The characteristics and reliabilities of the products are not restricted to this limitation)

Shipment Specification

